

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	1	("20020117697").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/11 16:47
L3	1	L2 and InP and InAlAs	US-PGPUB; USPAT	OR	OFF	2005/03/11 16:53
L4	45	InP near3 buffer and InAlAs near3 buffer	US-PGPUB; USPAT	OR	OFF	2005/03/11 16:54
L5	57	InP near3 buffer and InAlAs near3 buffer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 16:56
L6	2	JP-04093088-\$.did.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 16:58
L7	2	5 and TORIKAI	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/11 16:59
L8	1457	(257/186,189,190,438,458).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/11 17:24
L9	4	L8 and substrate near4 InAlAs and InP near2 buffer	US-PGPUB; USPAT	OR	OFF	2005/03/11 17:25
L12	7	"4816890"	US-PGPUB; USPAT	OR	OFF	2005/03/11 17:52
S1	4	"802593".ap.	US-PGPUB; USPAT	OR	OFF	2005/03/10 11:19
S2	0	(photodiode photo-diode photo adj diode) and buffer and field-controlling	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 11:33
S3	11	(photodiode photo-diode photo adj diode) and buffer and field adj controlling	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 11:33

S4	369	(HPT phototransistor photo-transistor photo adj transistor photodiode photo-diode photo adj diode) and InP and InAlAs	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 11:55
S6	377	(avalanche adj (photodiode photo-diode photo adj diode) APD) and (multiply multiplying multiplication amplify amplifying amplification) and (absorbing absorption) near light	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 13:36
S7	359	S6 and @pd>"19840410"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 12:40
S8	130	(avalanche adj (photodiode photo-diode photo adj diode) APD) and watanabe	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 13:37
S9	52	(avalanche adj (photodiode photo-diode photo adj diode) APD) and watanabe and (absorbing absorption) near light	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 13:49
S10	7	"5552629" and (absorbing absorption) near light	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 14:49
S11	39	S9 and @pd>"19951004"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/03/10 14:49
S12	1	("20020117697").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/10 17:00
S13	1457	(257/186,189,190,438,458).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/10 17:12
S14	1457	(257/186,189,190,438,458).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/11 17:23
S15	16	S14 and annular near3 electrode	US-PGPUB; USPAT	OR	OFF	2005/03/11 12:24